

XP04315 (XP4315)

Silicon NPN epitaxial planer transistor (Tr1)

Silicon PNP epitaxial planer transistor (Tr2)

For switching/digital circuits

Features

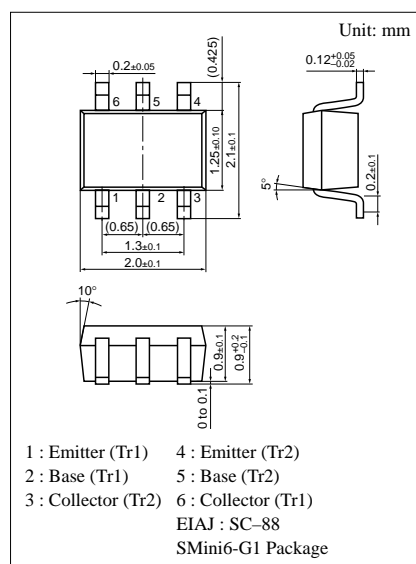
- Two elements incorporated into one package.
(Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half.

Basic Part Number of Element

- UNR1215(UN1215) + UNR1115(UN1115)

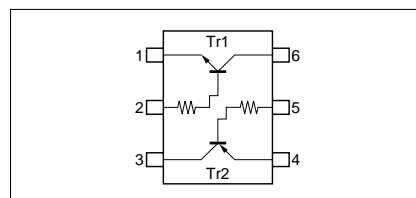
Absolute Maximum Ratings (Ta=25°C)

| | Parameter | Symbol | Ratings | Unit |
|---------|------------------------------|-----------|-------------|------|
| Tr1 | Collector to base voltage | V_{CBO} | 50 | V |
| | Collector to emitter voltage | V_{CEO} | 50 | V |
| | Collector current | I_C | 100 | mA |
| Tr2 | Collector to base voltage | V_{CBO} | -50 | V |
| | Collector to emitter voltage | V_{CEO} | -50 | V |
| | Collector current | I_C | -100 | mA |
| Overall | Total power dissipation | P_T | 150 | mW |
| | Junction temperature | T_j | 150 | °C |
| | Storage temperature | T_{stg} | -55 to +150 | °C |



Marking Symbol: CB

Internal Connection



Note) The Part number in the Parenthesis shows conventional part number.

■ Electrical Characteristics (T_a=25°C)

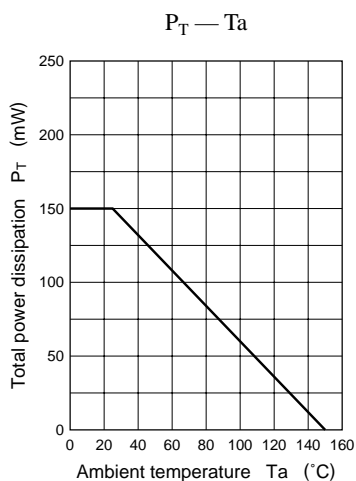
• Tr1

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|----------------------|---|------|-----|------|------|
| Collector to base voltage | V _{CBO} | I _C = 10μA, I _E = 0 | 50 | | | V |
| Collector to emitter voltage | V _{CEO} | I _C = 2mA, I _B = 0 | 50 | | | V |
| Collector cutoff current | I _{CBO} | V _{CB} = 50V, I _E = 0 | | | 0.1 | μA |
| | I _{CEO} | V _{CE} = 50V, I _B = 0 | | | 0.5 | μA |
| Emitter cutoff current | I _{EBO} | V _{EB} = 6V, I _C = 0 | | | 0.01 | mA |
| Forward current transfer ratio | h _{FE} | V _{CE} = 10V, I _C = 5mA | 160 | | 460 | |
| Collector to emitter saturation voltage | V _{CE(sat)} | I _C = 10mA, I _B = 0.3mA | | | 0.25 | V |
| Output voltage high level | V _{OH} | V _{CC} = 5V, V _B = 0.5V, R _L = 1kΩ | 4.9 | | | V |
| Output voltage low level | V _{OL} | V _{CC} = 5V, V _B = 2.5V, R _L = 1kΩ | | | 0.2 | V |
| Transition frequency | f _T | V _{CB} = 10V, I _E = -2mA, f = 200MHz | | 150 | | MHz |
| Input resistance | R _I | | -30% | 10 | +30% | kΩ |

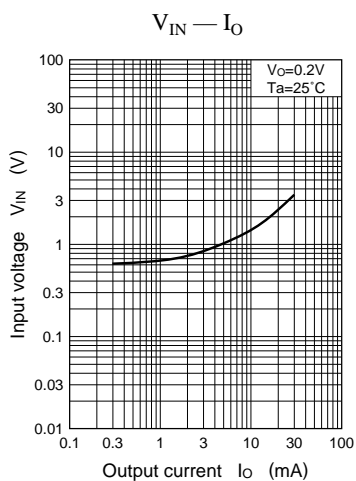
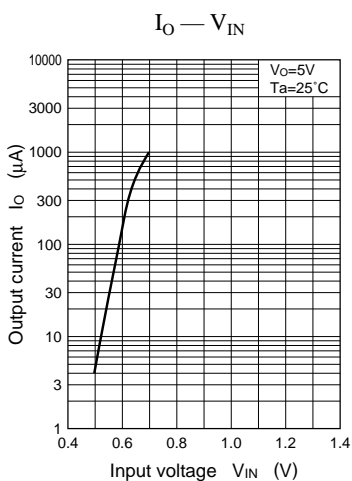
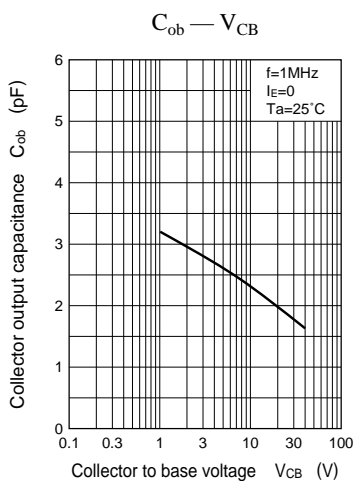
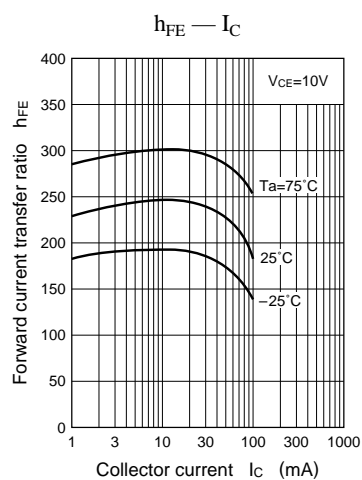
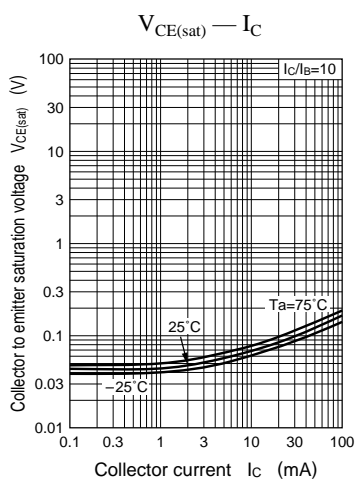
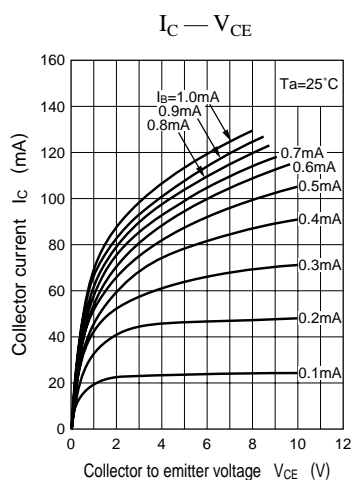
• Tr2

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|----------------------|--|------|-----|--------|------|
| Collector to base voltage | V _{CBO} | I _C = -10μA, I _E = 0 | -50 | | | V |
| Collector to emitter voltage | V _{CEO} | I _C = -2mA, I _B = 0 | -50 | | | V |
| Collector cutoff current | I _{CBO} | V _{CB} = -50V, I _E = 0 | | | - 0.1 | μA |
| | I _{CEO} | V _{CE} = -50V, I _B = 0 | | | - 0.5 | μA |
| Emitter cutoff current | I _{EBO} | V _{EB} = -6V, I _C = 0 | | | - 0.01 | mA |
| Forward current transfer ratio | h _{FE} | V _{CE} = -10V, I _C = -5mA | 160 | | 460 | |
| Collector to emitter saturation voltage | V _{CE(sat)} | I _C = -10mA, I _B = - 0.3mA | | | - 0.25 | V |
| Output voltage high level | V _{OH} | V _{CC} = -5V, V _B = - 0.5V, R _L = 1kΩ | -4.9 | | | V |
| Output voltage low level | V _{OL} | V _{CC} = -5V, V _B = -2.5V, R _L = 1kΩ | | | - 0.2 | V |
| Transition frequency | f _T | V _{CB} = -10V, I _E = 1mA, f = 200MHz | | 80 | | MHz |
| Input resistance | R _I | | -30% | 10 | +30% | kΩ |

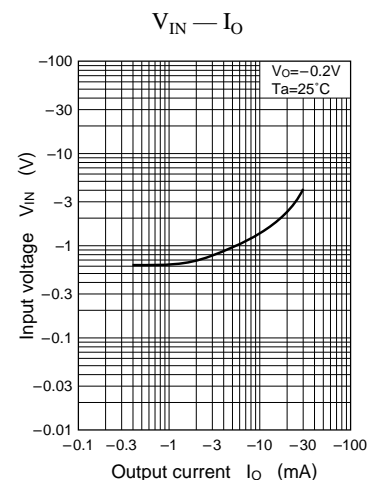
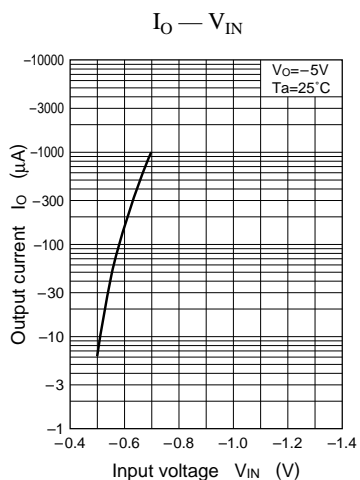
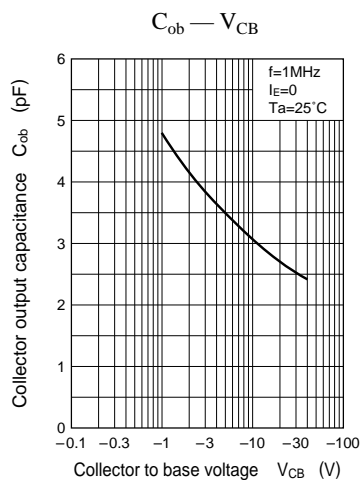
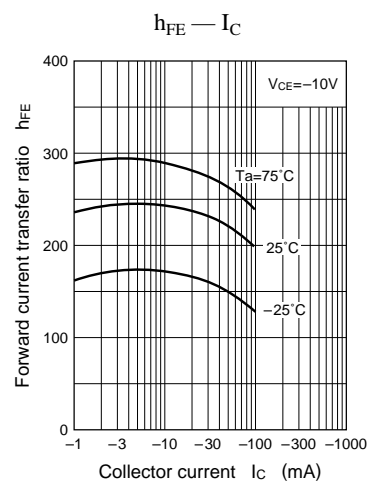
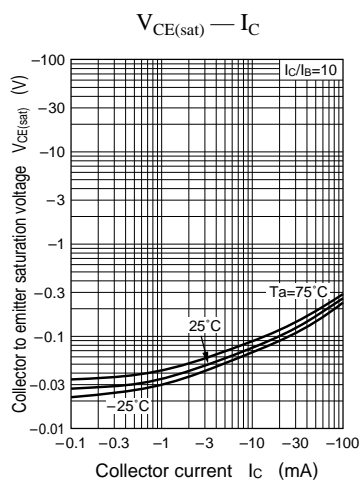
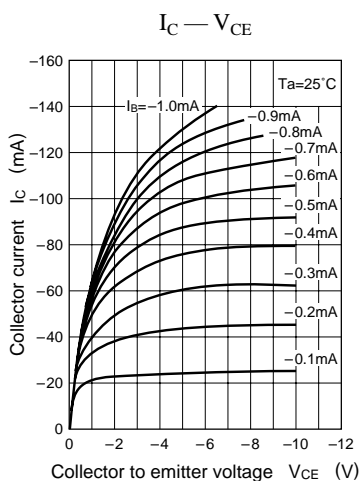
Common characteristics chart



Characteristics charts of Tr1



Characteristics charts of Tr2



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